

Dynamic Engineers Inc.

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 USA TEL: 1-281-870-8822 EMAIL:Sales@DynamicEng.com

H7 LC+) \$%GSgYf]Yg

7.0 x 5.0 mm

SMD High Precision Voltage Controlled TCXO

Features and Benefits

5MHz--52MHz Frequency range 3.3V and 5.0V Supply voltage CMOS and Clipped Sinewave Output waveform ±0.28ppm Stability Vs -40C -- +85C 7.0x5.0mm Size 5, 6.4, 8, 8.192, 10, 12.5, 12.8, 16, 16.384, 19.44, 25MHz for CMOS 8.192, 10, 12.5, 12.8, 16, 16.384, 19.44, 25MHz for Clipped Sinewave

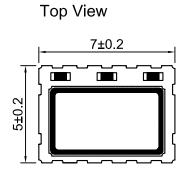
Typical Applications

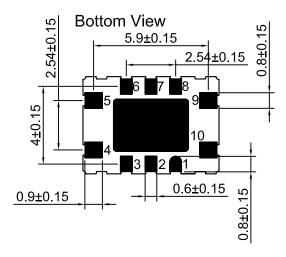
Femtocell, Base Stations WLAN / WiMAX / WiFi, Wireless Communications Mobile Phone

Mechanical Drawing & Pin Connections

Drawing No:

MD15001) -%



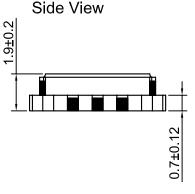


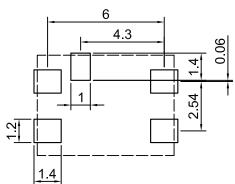
Pin Function #1 N

NC				
NC				
NC				
GND				
Output				
NC				
NC				
Tri-State Contro				
VDD				
VCON				

Unit in mm 1mm = 0.0394 inches

N Recommended Soldering Pattern







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Specifications

On a sifi and in	Com diversi	5.0V		3.3V		1124	
Specification	Conditon	Min.	Max.	Min.	Max.	Unit	
Supply Voltage Variation(VDD)	V _{DD±} 5%	4.75	5.25	3.135	3.465	V	
Frequency Range		5	52	5	52	MHz	
Standard Frequency	For CMOS For Clipped Sinewave		16.384,	10, 12.5, 12.8, 16, 19.44, 25 3, 16, 16.384, 19.44,		MHz	
	1 of Clipped Sillewave						
Frequency Tolerance			±2.0		±2.0	ppm	
Frequency Stability							
Vs Supply Voltage	±5% Change		±0.5		±0.5	ppm	
Vs Load	±10% Change		±0.2		±0.2	ppm	
Vs Aging			±1.0		±1.0	ppm	
Supply Current	CMOS	-	6	-	6	mΑ	
Supply Current	Clipped Sinewave	-	3.5	-	3.5	ША	
Output Level(CMOS)	Output High	90%V DD	-	90%V DD	-	V	
Output Level(CWO3)	Output Low	-	10%VDD	-	10%VDD		
	Duty	45	55	45	55	%	
Output Level(Clipped Sinewave)		0.8		0.8		Vp-p	
Load(CMOS)		15		15		pF	
Load(Clipped Sinewave)		10kohm//10pf		10kohm//10pf			
Control Voltage Range(VCTCXO)		0.5	2.5	0.5	2.5	V	
Pulling Range(VCTCXO)		±5	±12	±5	±12	ppm	
Vc Input Impedance(VCTCXO)		100		100		kohm	
Phase Noise@19.2MHz							
100Hz		-120		-120			
1KHz		-140		-140		dBc/Hz	
10KHz		-148		-148			
Start Time		-	2	-	2	mSec	
Tri State	Enable	3.5	-	2.31	-	V	
Tri-State	Disable	-	1.5	-	0.99		
Storage Temperature		-55	-125	-55	-125	°C	

Frequency Stability vs. Temperature

	±0.05PPM	±0.1PPM	±0.14PPM	±0.28PPM	±0.37PPM	±0.5PPM
-10°C to +60°C	Available	Available	Available	Available	Available	Available
-20°C to +70°C	Conditional	Available	Available	Available	Available	Available
-40°C to +85°C	Not Available	Not Available	Not Available	Available	Available	Available

Note: not all combination of options are available. Other specifications may be available upon request.